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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/752,642	01/07/2004	Naofumi Nakamura	790001-2042	4109
20999 7590 02/02/2009 FROMMER LAWRENCE & HAUG			EXAMINER	
745 FIFTH AVENUE- 10TH FL.			CHU, CHRIS C	
NEW YORK,	NY 10151		ART UNIT	PAPER NUMBER
			2815	
			MAIL DATE	DELIVERY MODE
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Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

Application No. Applicant(s) 10/752.642 NAKAMURA ET AL. Office Action Summary Examiner Art Unit CHRIS C. CHU 2815 -- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --Period for Reply A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS. WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION. Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication. If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b). Status 1) Responsive to communication(s) filed on 24 November 2008. 2a) This action is FINAL. 2b) This action is non-final. 3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213. Disposition of Claims 4) Claim(s) 1 - 14 is/are pending in the application. 4a) Of the above claim(s) 5 - 10, 13 and 14 is/are withdrawn from consideration. 5) Claim(s) _____ is/are allowed. 6) Claim(s) 1 - 3. 11 and 12 is/are rejected. 7) Claim(s) 4 is/are objected to. 8) Claim(s) _____ are subject to restriction and/or election requirement. Application Papers 9) The specification is objected to by the Examiner. 10) The drawing(s) filed on is/are; a) accepted or b) objected to by the Examiner. Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a). Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d). 11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152. Priority under 35 U.S.C. § 119 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. Attachment(s) 1) Notice of References Cited (PTO-892) 4) Interview Summary (PTO-413) Paper No(s)/Mail Date. Notice of Draftsperson's Patent Drawing Review (PTO-948) 5) Notice of Informal Patent Application

Information Disclosure Statement(s) (PTO/S5/08)
 Paper No(s)/Mail Date ______

6) Other:

Application/Control Number: 10/752,642 Page 2

Art Unit: 2815

DETAILED ACTION

Response to Pre-Appeal Brief

In view of the Pre-appeal brief filed on November 24, 2008, PROSECUTION IS
 HEREBY REOPENED. A new ground of rejection is set forth below.

To avoid abandonment of the application, appellant must exercise one of the following two options:

- file a reply under 37 CFR 1.11 1 (if this Office action is non-final) or a reply under 37
 CFR 1.113 (if this Office action is final); or,
 - (2) request reinstatement of the appeal.

If reinstatement of the appeal is requested, such request must be accompanied by a supplemental appeal brief, but no new amendments, affidavits (37 CFR 1.130, 1.131 or 1.132) or other evidence are permitted. See 37 CFR 1.193(b)(2).

Claim Rejections - 35 USC § 103

- The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all
 obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- Claims 1, 2, 11 and 12 are rejected under 35 U.S.C. 103(a) as being unpatentable over
 Pramanick et al. (U. S. Pat. No. 6,147,404) in view of Halliyal et al. (U. S. Pat. No. 6,731,006).

Application/Control Number: 10/752,642 Art Unit: 2815

Regarding claim 1, Pramanick et al. discloses in e.g., Fig. 4 a semiconductor device (200; column 2, line 47) having a multilayer structure (see e.g., Fig. 4), comprising:

- at least two wiring layers (101 and 204; column 4, lines 33 and 34), each formed in a wiring groove formed in a corresponding insulating film (105 and 108; column 3, lines 42 44 and column 4, line 39); and
- a via contact (the via contact 202; column 5, line 4) embedded, in a via hole (118; column 4, line 56) formed in an insulating film (116; column 4, lines 4 and 5) formed between the at least two layers (101 and 204) and made of a metal wiring material which is the same as that of the at least two wiring layers (101 and 204; column 4, lines 13 15, column 5, lines 4 6 and see e.g., Fig. 4).

Pramanick et al. does not disclose an additive within the metal wiring material of the via contact. Halliyal et al. teaches in e.g., Fig. 1H a metal wiring material (the material that is located in the via 116; column 6, lines 60 – 65) of the via contact (116; column 6, line 61) containing an additive (the dopant material; column 7, lines 1 – 6). It would have been obvious to one of ordinary skill in the art at the time when the invention was made to apply the dopant material of Halliyal et al. as the specific material to form the additive within the metal wiring material of the via contact of Pramanick et al. as taught by Halliyal et al. to reduce electromigration of copper or the movement of copper atoms along the channels or vias under the influence of electrical current (column 7, lines 6 – 10). Furthermore, the combined structure of Pramanick et al. and Halliyal et al. disclose the following limitation "the additive which is not contained in the metal wiring materials of the at least two wiring layers."

Application/Control Number: 10/752,642

Art Unit: 2815

Regarding claims 2 and 12, Pramanick et al., as modified, discloses in e.g., Fig. 4 the metal wiring material (101 and 204) being Cu (column 4, lines 13 – 15 of Pramanick et al.) and the additive (the dopant material) being Sn, Rh, Zn, A1, Ru, Cr, Pd, In, Mg, Co, Zr, Ti, Ag, Ir, Ni, Ge, Nb, B, Or Hr (column 7, lines 1 – 6 of Halliyal et al.).

Regarding claim 11, Pramanick et al. discloses in e.g., Fig. 4 a semiconductor device (200) comprising:

- a first metal wiring layer (101) made of a first wiring material (column 4, lines 13 –
 15), formed in a first wiring groove formed in a first insulating film (105) on a semiconductor substrate (the semiconductor substrate of the semiconductor device
 200; column 2, lines 24 28);
- a second insulating film (114) on the first insulating film (105) having the first wiring layer (101) embedded therein (see e.g., Fig. 4);
- a via contact (the via contact 202) embedded in a via hole (118) formed in the second insulating film (116; see e.g., Fig. 4), the via contact (the via contact 202) being made of the same wiring material as the first wiring material (column 5, lines 4 6, column 4, lines 13 15 and see e.g., Fig. 4);
- a third insulating film (116) on the second insulating film (114) having the via contact
 (202) formed therein (see e.g., Fig. 4); and
- a second metal wiring layer (204) embedded in a second wiring groove (the opening within the layer 108) formed in the third insulating film (108; see e.g., Fig. 4), the second metal wiring layer (204) being made of the same metal wiring material as the

Art Unit: 2815

metal wiring material of the first metal wiring layer (101; column 4, lines 13 – 15 and see e.g., Fig. 4).

Pramanick et al. does not disclose an additive within the metal wiring material of the via contact. Halliyal et al. teaches in e.g., Fig. 1H a metal wiring material (the material that is located in the via 116; column 6, lines 60-65) of the via contact (116; column 6, line 61) containing an additive (the dopant material; column 7, lines 1-6). It would have been obvious to one of ordinary skill in the art at the time when the invention was made to apply the dopant material of Halliyal et al. as the specific material to form the additive within the metal wiring material of the via contact of Pramanick et al. as taught by Halliyal et al. to reduce electromigration of copper or the movement of copper atoms along the channels or vias under the influence of electrical current (column 7, lines 6-10). Furthermore, the combined structure of Pramanick et al. and Halliyal et al. disclose the following limitation "the additive which is not contained in the metal wiring materials of the at least two wiring layers."

Claim 3 is rejected under 35 U.S.C. 103(a) as being unpatentable over Pramanick et al.
and Halliyal et al. as applied to claim 1 above, and further in view of Jan (U. S. Pat. No.
6,861,758).

While Pramanick et al. and Halliyal et al. disclose the use of the metal wiring material (101 and 204) being Al (column 4, lines 13 – 15), Pramanick et al. and Halliyal et al. do not disclose the additive being Cu or Si. Jan teaches in e.g., Fig. 9 an additive (the dopant material; column 2, lines 45 – 16) being Cu or Si (column 2, lines 49 – 51). It would have been obvious to one of ordinary skill in the art at the time when the invention was made to further apply the Cu or

Art Unit: 2815

Si of Jan as the specific material to form the additive within the metal wiring material of the via contact of Pramanick et al. and Halliyal et al. as taught by Jan to inhibit electromigration (column 3, lines 1 – 12).

Allowable Subject Matter

- Claim 4 is objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.
 - (A) Claim 4 contains allowable subject matter because none of references of record teach or suggest, either singularly or in combination, at least the limitation of a metal wiring material being Ag and the additive being Cu.

Response to Arguments

 Applicant's arguments with respect to claims 1 and 11 have been considered but are moot in view of the new ground(s) of rejection.

Conclusion

Any inquiry concerning this communication or earlier communications from the
examiner should be directed to CHRIS C. CHU whose telephone number is (571)272-1724. The
examiner can normally be reached on 11:30 - 8:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Kenneth Parker can be reached on 571-272-2298. The fax phone number for the

Application/Control Number: 10/752,642

Art Unit: 2815

organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

Chris C. Chu Primary Examiner Art Unit 2815

/Chris C. Chu/ Primary Examiner, Art Unit 2815 Monday, January 26, 2009